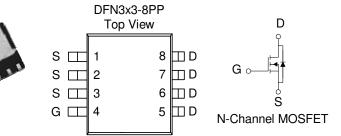
N-Channel 80-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
80	$35 @ V_{GS} = 10V$	9			
80	40 @ V _{GS} = 4.5V	8			



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			80	V	
Gate-Source Voltage	V_{GS}	±20	V		
	$T_A=25^{\circ}C$] 	<u>±</u> 9		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	±7	A	
Pulsed Drain Current ^b	I_{DM}	±75			
Continuous Source Current (Diode Conduction) ^a	I_S	16	A		
D D: : .: a	$T_A=25^{\circ}C$	D	3.5	\mathbf{w}	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	PD	2	VV	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Case ^a	t <= 5 sec	$R_{ heta JC}$	25	°C/W	
Maximum Junction-to-Ambient ^a	t <= 5 sec	$R_{ heta JA}$	50	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Downwatow	Cymbal	Test Conditions	Limits			TT .	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static	-						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{\mathrm{DS}} = V_{\mathrm{GS}}, I_{\mathrm{D}} = 250 \mathrm{uA}$	1			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}$			1	33 A	
Zeio Gate voltage Diani Culient	IDSS	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
D : G O D : A	******	$V_{GS} = 10 \text{ V}, I_{D} = 1 \text{ A}$		35		m()	
Drain-Source On-Resistance ^A	rdS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$			40	mΩ	
Forward Tranconductance ^A	g fs	$V_{DS} = 15 \text{ V}, I_{D} = 9 \text{ A}$		40		S	
Diode Forward Voltage	V_{SD}	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	Vr. 2 - 15 V Vr. 2 - 45 V		28			
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 9 \text{ A}$		13		пC	
Gate-Drain Charge	Q_{gd}			6		1 /	
Turn-On Delay Time	t _{d(on)}			6			
Rise Time	t _r	$V_{\rm DD} = 25$ V, $R_L = 25~\Omega$, ID = 1 A,		2		nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 V$		24			
Fall-Time	t_{f}			2			

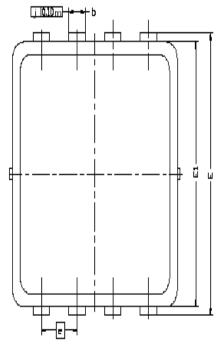
Notes

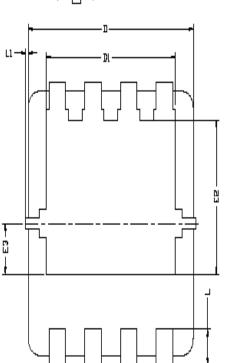
a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

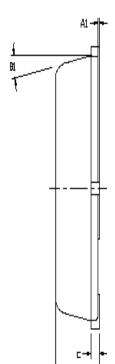
b. Guaranteed by design, not subject to production testing.

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Package Information







DIM,	HΩ	HOLLIMETERS			CNCHES		
	MIN	NOM	MAX	MIN	NOM	MAX	
h	0,700	0,87	0,900	0.0276	0,0315	M354	
AL	ָרָרָן, קרָרָן		1,05	ססס,		0.005	
Ь	0.24	0.30	0,35	0.009	0.012	0.014	
	뎔	<u>53</u>	띮	0.004	0.006	0,010	
	3.00 BSC			(.11B BS	Ĉ	
	2.35 BSC			Ċ.	093 BS	ľ	
	320 BSC]	126 BS	lÇ	
EL	3.00 BSC			0	.118 BS	Ç	
E5	1.75 BSC			Q,	069 B3		
E3	0.575 BSC			Ċ,	023 BS		
2	0.65 BSC			Ċ,	026 BS		
	0.30	0,40	150	0,0118	0,0157	0.0197	
	0		0.100	0		0.004	
B1	D,	10'	12'),	10'	15,	